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Understanding [Embedded - FPGAs \(Field Programmable Gate Array\)](#)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details

Product Status	Obsolete
Number of LABs/CLBs	7776
Number of Logic Elements/Cells	34992
Total RAM Bits	589824
Number of I/O	404
Number of Gates	2188742
Voltage - Supply	1.71V ~ 1.89V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 85°C (TJ)
Package / Case	560-LBGA Exposed Pad, Metal
Supplier Device Package	560-MBGA (42.5x42.5)
Purchase URL	https://www.e-xfl.com/product-detail/xilinx/xcv1600e-6bg560c

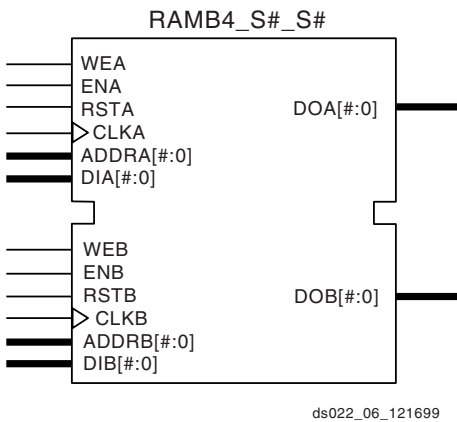


Figure 6: Dual-Port Block SelectRAM

Table 5 shows the depth and width aspect ratios for the block SelectRAM. The Virtex-E block SelectRAM also includes dedicated routing to provide an efficient interface with both CLBs and other block SelectRAMs. Refer to XAPP130 for block SelectRAM timing waveforms.

Table 5: Block SelectRAM Port Aspect Ratios

Width	Depth	ADDR Bus	Data Bus
1	4096	ADDR<11:0>	DATA<0>
2	2048	ADDR<10:0>	DATA<1:0>
4	1024	ADDR<9:0>	DATA<3:0>
8	512	ADDR<8:0>	DATA<7:0>
16	256	ADDR<7:0>	DATA<15:0>

Programmable Routing Matrix

It is the longest delay path that limits the speed of any worst-case design. Consequently, the Virtex-E routing architecture and its place-and-route software were defined in a joint optimization process. This joint optimization minimizes long-path delays, and consequently, yields the best system performance.

The joint optimization also reduces design compilation times because the architecture is software-friendly. Design cycles are correspondingly reduced due to shorter design iteration times.

Local Routing

The VersaBlock provides local routing resources (see Figure 7), providing three types of connections:

- Interconnections among the LUTs, flip-flops, and GRM
- Internal CLB feedback paths that provide high-speed connections to LUTs within the same CLB, chaining them together with minimal routing delay

- Direct paths that provide high-speed connections between horizontally adjacent CLBs, eliminating the delay of the GRM.

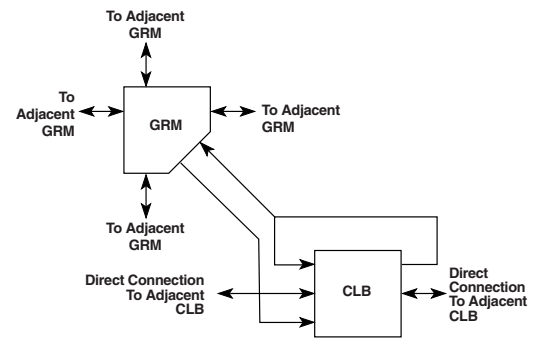


Figure 7: Virtex-E Local Routing

General Purpose Routing

Most Virtex-E signals are routed on the general purpose routing, and consequently, the majority of interconnect resources are associated with this level of the routing hierarchy. General-purpose routing resources are located in horizontal and vertical routing channels associated with the CLB rows and columns and are as follows:

- Adjacent to each CLB is a General Routing Matrix (GRM). The GRM is the switch matrix through which horizontal and vertical routing resources connect, and is also the means by which the CLB gains access to the general purpose routing.
- 24 single-length lines route GRM signals to adjacent GRMs in each of the four directions.
- 72 buffered Hex lines route GRM signals to another GRMs six-blocks away in each one of the four directions. Organized in a staggered pattern, Hex lines are driven only at their endpoints. Hex-line signals can be accessed either at the endpoints or at the midpoint (three blocks from the source). One third of the Hex lines are bidirectional, while the remaining ones are uni-directional.
- 12 Longlines are buffered, bidirectional wires that distribute signals across the device quickly and efficiently. Vertical Longlines span the full height of the device, and horizontal ones span the full width of the device.

I/O Routing

Virtex-E devices have additional routing resources around their periphery that form an interface between the CLB array and the IOBs. This additional routing, called the VersaRing, facilitates pin-swapping and pin-locking, such that logic redesigns can adapt to existing PCB layouts. Time-to-market is reduced, since PCBs and other system components can be manufactured while the logic design is still in progress.

The DLL also operates as a clock mirror. By driving the output from a DLL off-chip and then back on again, the DLL can be used to deskew a board level clock among multiple devices.

To guarantee that the system clock is operating correctly prior to the FPGA starting up after configuration, the DLL can delay the completion of the configuration process until after it has achieved lock. For more information about DLL functionality, see the Design Consideration section of the data sheet.

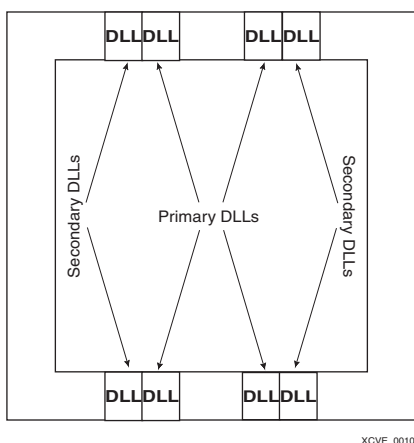


Figure 10: DLL Locations

Boundary Scan

Virtex-E devices support all the mandatory Boundary Scan instructions specified in the IEEE standard 1149.1. A Test Access Port (TAP) and registers are provided that implement the EXTEST, INTEST, SAMPLE/PRELOAD, BYPASS, IDCODE, USERCODE, and HIGHZ instructions. The TAP

also supports two internal scan chains and configuration/readback of the device.

The JTAG input pins (TDI, TMS, TCK) do not have a V_{CCO} requirement and operate with either 2.5 V or 3.3 V input signalling levels. The output pin (TDO) is sourced from the V_{CCO} in bank 2, and for proper operation of LVTTTL 3.3 V levels, the bank should be supplied with 3.3 V.

Boundary Scan operation is independent of individual IOB configurations, and unaffected by package type. All IOBs, including un-bonded ones, are treated as independent 3-state bidirectional pins in a single scan chain. Retention of the bidirectional test capability after configuration facilitates the testing of external interconnections, provided the user design or application is turned off.

Table 6 lists the Boundary Scan instructions supported in Virtex-E FPGAs. Internal signals can be captured during EXTEST by connecting them to un-bonded or unused IOBs. They can also be connected to the unused outputs of IOBs defined as unidirectional input pins.

Before the device is configured, all instructions except USER1 and USER2 are available. After configuration, all instructions are available. During configuration, it is recommended that those operations using the Boundary Scan register (SAMPLE/PRELOAD, INTEST, EXTEST) not be performed.

In addition to the test instructions outlined above, the Boundary Scan circuitry can be used to configure the FPGA, and also to read back the configuration data.

Figure 11 is a diagram of the Virtex-E Series Boundary Scan logic. It includes three bits of Data Register per IOB, the IEEE 1149.1 Test Access Port controller, and the Instruction Register with decodes.

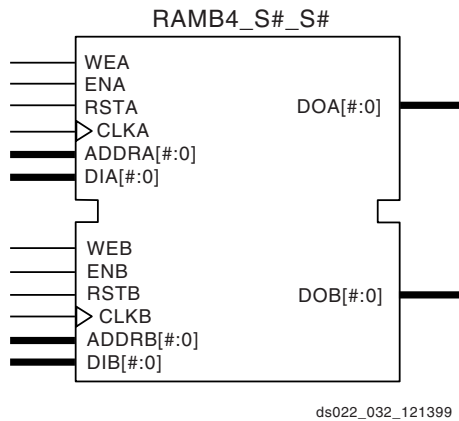


Figure 31: Dual-Port Block SelectRAM+ Memory

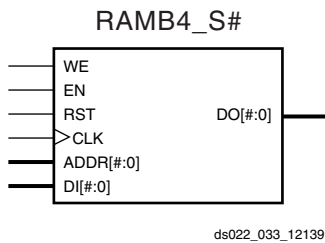


Figure 32: Single-Port Block SelectRAM+ Memory

Table 14: Available Library Primitives

Primitive	Port A Width	Port B Width
RAMB4_S1	1	N/A
RAMB4_S1_S1		1
RAMB4_S1_S2		2
RAMB4_S1_S4		4
RAMB4_S1_S8		8
RAMB4_S1_S16		16
RAMB4_S2	2	N/A
RAMB4_S2_S2		2
RAMB4_S2_S4		4
RAMB4_S2_S8		8
RAMB4_S2_S16		16
RAMB4_S4	4	N/A
RAMB4_S4_S4		4
RAMB4_S4_S8		8
RAMB4_S4_S16		16
RAMB4_S8	8	N/A
RAMB4_S8_S8		8
RAMB4_S8_S16		16
RAMB4_S16	16	N/A
RAMB4_S16_S16		16

Port Signals

Each block SelectRAM+ port operates independently of the others while accessing the same set of 4096 memory cells.

Table 15 describes the depth and width aspect ratios for the block SelectRAM+ memory.

Table 15: Block SelectRAM+ Port Aspect Ratios

Width	Depth	ADDR Bus	Data Bus
1	4096	ADDR<11:0>	DATA<0>
2	2048	ADDR<10:0>	DATA<1:0>
4	1024	ADDR<9:0>	DATA<3:0>
8	512	ADDR<8:0>	DATA<7:0>
16	256	ADDR<7:0>	DATA<15:0>

Clock—CLK[A/B]

Each port is fully synchronous with independent clock pins. All port input pins have setup time referenced to the port CLK pin. The data output bus has a clock-to-out time referenced to the CLK pin.

Enable—EN[A/B]

The enable pin affects the read, write and reset functionality of the port. Ports with an inactive enable pin keep the output pins in the previous state and do not write data to the memory cells.

Write Enable—WE[A/B]

Activating the write enable pin allows the port to write to the memory cells. When active, the contents of the data input bus are written to the RAM at the address pointed to by the address bus, and the new data also reflects on the data out bus. When inactive, a read operation occurs and the contents of the memory cells referenced by the address bus reflect on the data out bus.

Reset—RST[A/B]

The reset pin forces the data output bus latches to zero synchronously. This does not affect the memory cells of the RAM and does not disturb a write operation on the other port.

Address Bus—ADDR[A/B]<#:0>

The address bus selects the memory cells for read or write. The width of the port determines the required width of this bus as shown in Table 15.

Data In Bus—DI[A/B]<#:0>

The data in bus provides the new data value to be written into the RAM. This bus and the port have the same width, as shown in Table 15.

Data Output Bus—DO[AIB]<#:0>

The data out bus reflects the contents of the memory cells referenced by the address bus at the last active clock edge. During a write operation, the data out bus reflects the data in bus. The width of this bus equals the width of the port. The allowed widths appear in [Table 15](#).

Inverting Control Pins

The four control pins (CLK, EN, WE and RST) for each port have independent inversion control as a configuration option.

Address Mapping

Each port accesses the same set of 4096 memory cells using an addressing scheme dependent on the width of the port.

The physical RAM location addressed for a particular width are described in the following formula (of interest only when the two ports use different aspect ratios).

$$\text{Start} = ((\text{ADDR}_{\text{port}} + 1) * \text{Width}_{\text{port}}) - 1$$

$$\text{End} = \text{ADDR}_{\text{port}} * \text{Width}_{\text{port}}$$

Conflict Resolution

The block SelectRAM+ memory is a true dual-read/write port RAM that allows simultaneous access of the same memory cell from both ports. When one port writes to a given memory cell, the other port must not address that memory cell (for a write or a read) within the clock-to-clock setup window. The following lists specifics of port and memory cell write conflict resolution.

- If both ports write to the same memory cell simultaneously, violating the clock-to-clock setup requirement, consider the data stored as invalid.
- If one port attempts a read of the same memory cell the other simultaneously writes, violating the clock-to-clock setup requirement, the following occurs.
 - The write succeeds
 - The data out on the writing port accurately reflects the data written.
 - The data out on the reading port is invalid.

Conflicts do not cause any physical damage.

[Table 16](#) shows low order address mapping for each port width.

Table 16: Port Address Mapping

Port Width	Port Addresses																
1	4095...	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
2	2047...	07		06		05		04		03		02		01		00	
4	1023...	03				02				01				00			
8	511...	01								00							
16	255...	00															

Creating Larger RAM Structures

The block SelectRAM+ columns have specialized routing to allow cascading blocks together with minimal routing delays. This achieves wider or deeper RAM structures with a smaller timing penalty than when using normal routing channels.

Location Constraints

Block SelectRAM+ instances can have LOC properties attached to them to constrain the placement. The block SelectRAM+ placement locations are separate from the CLB location naming convention, allowing the LOC properties to transfer easily from array to array.

The LOC properties use the following form.

$$\text{LOC} = \text{RAMB4_R\#C\#}$$

RAMB4_R0C0 is the upper left RAMB4 location on the device.

Single Port Timing

[Figure 33](#) shows a timing diagram for a single port of a block SelectRAM+ memory. The block SelectRAM+ AC switching characteristics are specified in the data sheet. The block SelectRAM+ memory is initially disabled.

At the first rising edge of the CLK pin, the ADDR, DI, EN, WE, and RST pins are sampled. The EN pin is High and the WE pin is Low indicating a read operation. The DO bus contains the contents of the memory location, 0x00, as indicated by the ADDR bus.

At the second rising edge of the CLK pin, the ADDR, DI, EN, WR, and RST pins are sampled again. The EN and WE pins are High indicating a write operation. The DO bus mirrors the DI bus. The DI bus is written to the memory location 0x0F.

At the third rising edge of the CLK pin, the ADDR, DI, EN, WR, and RST pins are sampled again. The EN pin is High and the WE pin is Low indicating a read operation. The DO bus contains the contents of the memory location 0x7E as indicated by the ADDR bus.

At the fourth rising edge of the CLK pin, the ADDR, DI, EN, WR, and RST pins are sampled again. The EN pin is Low

Verilog Initialization Example

```

module MYMEM (CLK, WE, ADDR, DIN, DOUT);
input CLK, WE;
input [8:0] ADDR;
input [7:0] DIN;
output [7:0] DOUT;

wire logic0, logic1;

//synopsys dc_script_begin
//set_attribute ram0 INIT_00
"0123456789ABCDEF0123456789ABCDEF0123456789ABCDEF0123456789ABCDEF" -type string
//set_attribute ram0 INIT_01
"FEDCBA9876543210FEDCBA9876543210FEDCBA9876543210FEDCBA9876543210" -type string
//synopsys dc_script_end

assign logic0 = 1'b0;
assign logic1 = 1'b1;

RAMB4_S8 ram0 (.WE(WE), .EN(logic1), .RST(logic0), .CLK(CLK), .ADDR(ADDR), .DI(DIN),
.DO(DOUT));
//synopsys translate_off
defparam ram0.INIT_00 =
256h'0123456789ABCDEF0123456789ABCDEF0123456789ABCDEF0123456789ABCDEF;
defparam ram0.INIT_01 =
256h'FEDCBA9876543210FEDCBA9876543210FEDCBA9876543210FEDCBA9876543210;
//synopsys translate_on
endmodule

```

Using SelectI/O

The Virtex-E FPGA series includes a highly configurable, high-performance I/O resource, called SelectI/O™ to provide support for a wide variety of I/O standards. The SelectI/O resource is a robust set of features including programmable control of output drive strength, slew rate, and input delay and hold time. Taking advantage of the flexibility and SelectI/O features and the design considerations described in this document can improve and simplify system level design.

Introduction

As FPGAs continue to grow in size and capacity, the larger and more complex systems designed for them demand an increased variety of I/O standards. Furthermore, as system clock speeds continue to increase, the need for high performance I/O becomes more important.

While chip-to-chip delays have an increasingly substantial impact on overall system speed, the task of achieving the desired system performance becomes more difficult with the proliferation of low-voltage I/O standards. SelectI/O, the revolutionary input/output resources of Virtex-E devices, resolve this potential problem by providing a highly configurable, high-performance alternative to the I/O resources of more conventional programmable devices. Virtex-E SelectI/O features combine the flexibility and time-to-market advantages of programmable logic with the high performance previously available only with ASICs and custom ICs.

Each SelectI/O block can support up to 20 I/O standards. Supporting such a variety of I/O standards allows the support of a wide variety of applications, from general purpose standard applications to high-speed low-voltage memory buses.

SelectI/O blocks also provide selectable output drive strengths and programmable slew rates for the LVTTTL output buffers, as well as an optional, programmable weak pull-up, weak pull-down, or weak “keeper” circuit ideal for use in external bussing applications.

Each Input/Output Block (IOB) includes three registers, one each for the input, output, and 3-state signals within the IOB. These registers are optionally configurable as either a D-type flip-flop or as a level sensitive latch.

The input buffer has an optional delay element used to guarantee a zero hold time requirement for input signals registered within the IOB.

The Virtex-E SelectI/O features also provide dedicated resources for input reference voltage (V_{REF}) and output source voltage (V_{CCO}), along with a convenient banking system that simplifies board design.

By taking advantage of the built-in features and wide variety of I/O standards supported by the SelectI/O features, system-level design and board design can be greatly simplified and improved.

Virtex-E Electrical Characteristics

Definition of Terms

Electrical and switching characteristics are specified on a per-speed-grade basis and can be designated as Advance, Preliminary, or Production. Each designation is defined as follows:

Advance: These speed files are based on simulations only and are typically available soon after device design specifications are frozen. Although speed grades with this designation are considered relatively stable and conservative, some under-reporting might still occur.

Preliminary: These speed files are based on complete ES (engineering sample) silicon characterization. Devices and speed grades with this designation are intended to give a better indication of the expected performance of production silicon. The probability of under-reporting delays is greatly reduced as compared to Advance data.

Production: These speed files are released once enough production silicon of a particular device family member has been characterized to provide full correlation between speed files and devices over numerous production lots. There is no under-reporting of delays, and customers receive formal notification of any subsequent changes. Typically, the slowest speed grades transition to Production before faster speed grades.

All specifications are representative of worst-case supply voltage and junction temperature conditions. The parameters included are common to popular designs and typical applications. Contact the factory for design considerations requiring more detailed information.

Table 1 correlates the current status of each Virtex-E device with a corresponding speed file designation.

Table 1: Virtex-E Device Speed Grade Designations

Device	Speed Grade Designations		
	Advance	Preliminary	Production
XCV50E			-8, -7, -6
XCV100E			-8, -7, -6
XCV200E			-8, -7, -6
XCV300E			-8, -7, -6
XCV400E			-8, -7, -6
XCV600E			-8, -7, -6
XCV1000E			-8, -7, -6
XCV1600E			-8, -7, -6
XCV2000E			-8, -7, -6
XCV2600E			-8, -7, -6
XCV3200E			-8, -7, -6

All specifications are subject to change without notice.

Virtex-E Pin-to-Pin Input Parameter Guidelines

All devices are 100% functionally tested. Listed below are representative values for typical pin locations and normal clock loading. Values are expressed in nanoseconds unless otherwise noted

Global Clock Set-Up and Hold for LVTTL Standard, *with DLL*

Description ⁽¹⁾	Symbol	Device	Speed Grade ^(2, 3)				Units
			Min	-8	-7	-6	
Input Setup and Hold Time Relative to Global Clock Input Signal for LVTTL Standard. For data input with different standards, adjust the setup time delay by the values shown in IOB Input Switching Characteristics Standard Adjustments , page 8.							
No Delay	T _{PSDLL} /T _{PHDLL}	XCV50E	1.5 / −0.4	1.5 / −0.4	1.6 / −0.4	1.7 / −0.4	ns
Global Clock and IFF, with DLL		XCV100E	1.5 / −0.4	1.5 / −0.4	1.6 / −0.4	1.7 / −0.4	ns
		XCV200E	1.5 / −0.4	1.5 / −0.4	1.6 / −0.4	1.7 / −0.4	ns
		XCV300E	1.5 / −0.4	1.5 / −0.4	1.6 / −0.4	1.7 / −0.4	ns
		XCV400E	1.5 / −0.4	1.5 / −0.4	1.6 / −0.4	1.7 / −0.4	ns
		XCV600E	1.5 / −0.4	1.5 / −0.4	1.6 / −0.4	1.7 / −0.4	ns
		XCV1000E	1.5 / −0.4	1.5 / −0.4	1.6 / −0.4	1.7 / −0.4	ns
		XCV1600E	1.5 / −0.4	1.5 / −0.4	1.6 / −0.4	1.7 / −0.4	ns
		XCV2000E	1.5 / −0.4	1.5 / −0.4	1.6 / −0.4	1.7 / −0.4	ns
		XCV2600E	1.5 / −0.4	1.5 / −0.4	1.6 / −0.4	1.7 / −0.4	ns
XCV3200E	1.5 / −0.4	1.5 / −0.4	1.6 / −0.4	1.7 / −0.4	ns		

Notes:

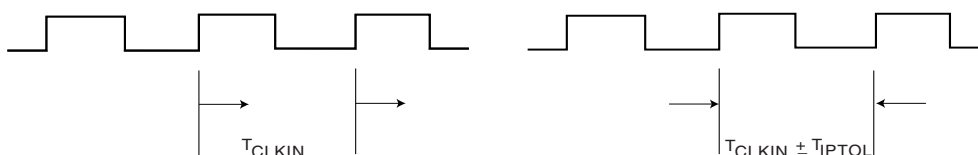
1. IFF = Input Flip-Flop or Latch
2. Setup time is measured relative to the Global Clock input signal with the fastest route and the lightest load. Hold time is measured relative to the Global Clock input signal with the slowest route and heaviest load.
3. DLL output jitter is already included in the timing calculation.

DLL Timing Parameters

All devices are 100 percent functionally tested. Because of the difficulty in directly measuring many internal timing parameters, those parameters are derived from benchmark timing patterns. The following guidelines reflect worst-case values across the recommended operating conditions.

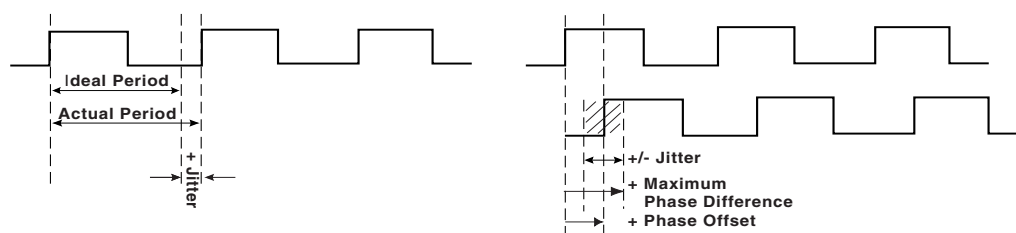
Description	Symbol	F _{CLKIN}	Speed Grade						Units
			-8		-7		-6		
			Min	Max	Min	Max	Min	Max	
Input Clock Frequency (CLKDLLHF)	FCLKINHF		60	350	60	320	60	275	MHz
Input Clock Frequency (CLKDLL)	FCLKINLF		25	160	25	160	25	135	MHz
Input Clock Low/High Pulse Width	T _{DLLPW}	≥2□5 MHz	5.0		5.0		5.0		ns
		≥□50 MHz	3.0		3.0		3.0		ns
		≥100 MHz	2.4		2.4		2.4		ns
		≥□150 MHz	2.0		2.0		2.0		ns
		≥□200 MHz	1.8		1.8		1.8		ns
		≥□250 MHz	1.5		1.5		1.5		ns
		≥□300 MHz	1.3		1.3		NA		ns

Period Tolerance: the allowed input clock period change in nanoseconds.



Output Jitter: the difference between an ideal reference clock edge and the actual design.

Phase Offset and Maximum Phase Difference



ds022_24_091200

Figure 4: DLL Timing Waveforms

Date	Version	Revision
07/23/01	2.2	<ul style="list-style-type: none"> Under Absolute Maximum Ratings, changed (T_{SOL}) to 220 °C. Changes made to SSTL symbol names in IOB Input Switching Characteristics Standard Adjustments table.
07/26/01	2.3	<ul style="list-style-type: none"> Removed T_{SOL} parameter and added footnote to Absolute Maximum Ratings table.
9/18/01	2.4	<ul style="list-style-type: none"> Reworded power supplies footnote to Absolute Maximum Ratings table.
10/25/01	2.5	<ul style="list-style-type: none"> Updated the speed grade designations used in data sheets, and added Table 1, which shows the current speed grade designation for each device. Added XCV2600E and XCV3200E values to DC Characteristics Over Recommended Operating Conditions and Power-On Power Supply Requirements tables.
11/09/01	2.6	<ul style="list-style-type: none"> Updated the Power-On Power Supply Requirements table.
02/01/02	2.7	<ul style="list-style-type: none"> Updated footnotes to the DC Input and Output Levels and DLL Clock Tolerance, Jitter, and Phase Information tables.
07/17/02	2.8	<ul style="list-style-type: none"> Data sheet designation upgraded from Preliminary to Production. Removed mention of MIL-M-38510/605 specification. Added link to XAPP158 from the Power-On Power Supply Requirements section.
09/10/02	2.9	<ul style="list-style-type: none"> Revised V_{IN} in Absolute Maximum Ratings table. Added Clock CLK switching characteristics to Table 2, “IOB Input Switching Characteristics,” on page 6 and IOB Output Switching Characteristics, Figure 1.
12/22/02	2.9.1	<ul style="list-style-type: none"> Added footnote regarding V_{IN} PCI compliance to Absolute Maximum Ratings table. The fastest ramp rate is 0V to nominal voltage in 2 ms
03/14/03	2.9.2	<ul style="list-style-type: none"> Under Power-On Power Supply Requirements, the fastest ramp rate is no longer a "suggested" rate.

Virtex-E Data Sheet

The Virtex-E Data Sheet contains the following modules:

- DS022-1, Virtex-E 1.8V FPGAs:
[Introduction and Ordering Information \(Module 1\)](#)
- DS022-2, Virtex-E 1.8V FPGAs:
[Functional Description \(Module 2\)](#)
- DS022-3, Virtex-E 1.8V FPGAs:
DC and Switching Characteristics (Module 3)
- DS022-4, Virtex-E 1.8V FPGAs:
[Pinout Tables \(Module 4\)](#)

Virtex-E Pin Definitions

Pin Name	Dedicated Pin	Direction	Description
GCK0, GCK1, GCK2, GCK3	Yes	Input	Clock input pins that connect to Global Clock Buffers.
M0, M1, M2	Yes	Input	Mode pins are used to specify the configuration mode.
CCLK	Yes	Input or Output	The configuration Clock I/O pin: it is an input for SelectMAP and slave-serial modes, and output in master-serial mode. After configuration, it is input only, logic level = Don't Care.
PROGRAM	Yes	Input	Initiates a configuration sequence when asserted Low.
DONE	Yes	Bidirectional	Indicates that configuration loading is complete, and that the start-up sequence is in progress. The output can be open drain.
INIT	No	Bidirectional (Open-drain)	When Low, indicates that the configuration memory is being cleared. The pin becomes a user I/O after configuration.
BUSY/DOUT	No	Output	In SelectMAP mode, BUSY controls the rate at which configuration data is loaded. The pin becomes a user I/O after configuration unless the SelectMAP port is retained. In bit-serial modes, DOUT provides preamble and configuration data to downstream devices in a daisy-chain. The pin becomes a user I/O after configuration.
D0/DIN, D1, D2, D3, D4, D5, D6, D7	No	Input or Output	In SelectMAP mode, D0-7 are configuration data pins. These pins become user I/Os after configuration unless the SelectMAP port is retained. In bit-serial modes, DIN is the single data input. This pin becomes a user I/O after configuration.
WRITE	No	Input	In SelectMAP mode, the active-low Write Enable signal. The pin becomes a user I/O after configuration unless the SelectMAP port is retained.
CS	No	Input	In SelectMAP mode, the active-low Chip Select signal. The pin becomes a user I/O after configuration unless the SelectMAP port is retained.
TDI, TDO, TMS, TCK	Yes	Mixed	Boundary-scan Test-Access-Port pins, as defined in IEEE1149.1.
DXN, DXP	Yes	N/A	Temperature-sensing diode pins. (Anode: DXP, cathode: DXN)
V _{CCINT}	Yes	Input	Power-supply pins for the internal core logic.
V _{CCO}	Yes	Input	Power-supply pins for the output drivers (subject to banking rules)
V _{REF}	No	Input	Input threshold voltage pins. Become user I/Os when an external threshold voltage is not needed (subject to banking rules).
GND	Yes	Input	Ground

Table 10: BG352 — XCV100E, XCV200E, XCV300E

Bank	Pin Description	Pin #
6	IO_L74P_Y	R25
6	IO_L75N	R26
6	IO_L75P	P24
6	IO	P23 ¹
6	IO	N26
7	IO_L76N_YY	N25
7	IO_L76P_YY	N24
7	IO	M26 ¹
7	IO_L77N	M25
7	IO_L77P	M24
7	IO_L78N_Y	M23
7	IO_VREF_7_L78P_Y	L26
7	IO_L79N_YY	K25
7	IO_L79P_YY	L24
7	IO	L23 ¹
7	IO_L80N	J26
7	IO_L80P	J25
7	IO	K24 ¹
7	IO_L81N_YY	K23
7	IO_L81P_YY	H25
7	IO_L82N_Y	J23
7	IO_VREF_7_L82P_Y	G26
7	IO_L83N_Y	G25
7	IO_L83P_Y	H24
7	IO	H23
7	IO	F26 ¹
7	IO	F25 ¹
7	IO_L84N_Y	G24
7	IO_VREF_7_L84P_Y	D26
7	IO_L85N_YY	E25
7	IO_L85P_YY	F24
7	IO	F23 ¹
7	IO_L86N_YY	D25

Table 10: BG352 — XCV100E, XCV200E, XCV300E

Bank	Pin Description	Pin #
7	IO_VREF_7_L86P_YY	E24 ²
7	IO	C26
7	IO	E23 ¹
7	IO	D24 ¹
7	IO	C25
NA	TDI	B3
NA	TDO	D4
NA	CCLK	C3
NA	TCK	C24
NA	TMS	D23
NA	PROGRAM	AC4
NA	DONE	AD3
NA	DXN	AD23
NA	DXP	AE24
NA	M2	AC23
NA	M0	AD24
NA	M1	AB23
NA	VCCINT	A20
NA	VCCINT	B16
NA	VCCINT	C14
NA	VCCINT	D12
NA	VCCINT	D10
NA	VCCINT	K4
NA	VCCINT	L1
NA	VCCINT	P2
NA	VCCINT	T1
NA	VCCINT	W2
NA	VCCINT	AC10
NA	VCCINT	AF11
NA	VCCINT	AE14
NA	VCCINT	AF16
NA	VCCINT	AE19

BG432 Differential Pin Pairs

Virtex-E devices have differential pin pairs that can also provide other functions when not used as a differential pair. A ✓ in the AO column indicates that the pin pair can be used as an asynchronous output for all devices provided in this package. Pairs with a note number in the AO column are device dependent. They can have asynchronous outputs if the pin pair are in the same CLB row and column in the device. Numbers in this column refer to footnotes that indicate which devices have pin pairs that can be asynchronous outputs. The Other Functions column indicates alternative function(s) not available when the pair is used as a differential pair or differential clock.

Table 13: BG432 Differential Pin Pair Summary
XCV300E, XCV400E, XC600E

Pair	Bank	P Pin	N Pin	AO	Other Functions
Global Differential Clock					
0	4	AL16	AH15	NA	IO_DLL_L86P
1	5	AK16	AL17	NA	IO_DLL_L86N
2	1	A16	B16	NA	IO_DLL_L16P
3	0	D17	C17	NA	IO_DLL_L16N
IO LVDS					
Total Outputs: 137, Asynchronous Output Pairs: 63					
0	0	D27	B29	1	-
1	0	C27	B28	✓	-
2	0	A28	D26	✓	VREF
3	0	C26	B27	2	-
4	0	A27	D25	✓	-
5	0	C25	D24	✓	VREF
6	0	D23	B25	1	-
7	0	B24	C24	1	VREF
8	0	A24	D22	✓	VREF
9	0	B22	C22	✓	-
10	0	D20	C21	✓	-
11	0	C20	B21	✓	-
12	0	D19	A20	✓	-
13	0	A19	B19	✓	VREF
14	0	D18	B18	1	-
15	0	B17	C18	1	VREF

Table 13: BG432 Differential Pin Pair Summary
XCV300E, XCV400E, XC600E

Pair	Bank	P Pin	N Pin	AO	Other Functions
16	1	B16	C17	NA	IO_LVDS_DLL
17	1	B15	A15	1	VREF
18	1	D15	C15	1	-
19	1	A13	B14	✓	VREF
20	1	D14	B13	✓	-
21	1	B12	C13	✓	-
22	1	C12	D13	✓	-
23	1	C11	D12	✓	-
24	1	C10	B10	✓	VREF
25	1	D10	C9	1	VREF
26	1	B8	A8	1	-
27	1	B7	C8	✓	VREF
28	1	A6	D8	✓	-
29	1	D7	B6	2	-
30	1	C6	A5	✓	VREF
31	1	D6	B5	✓	-
32	1	C5	A4	1	-
33	1	D5	B4	✓	CS, WRITE
34	2	D3	C2	✓	DIN, D0, BUSY
35	2	D2	E4	3	-
36	2	D1	E3	4	-
37	2	E2	F4	1	VREF
38	2	E1	F3	5	-
39	2	F2	G4	1	-
40	2	G3	G2	✓	VREF
41	2	H3	H2	4	-
42	2	H1	J4	1	VREF
43	2	J2	K4	✓	D1
44	2	K2	K1	✓	D2
45	2	L2	M4	4	-
46	2	M3	M2	1	-
47	2	N4	N3	1	-

Table 13: BG432 Differential Pin Pair Summary
XCV300E, XCV400E, XC600E

Pair	Bank	P Pin	N Pin	AO	Other Functions
48	2	N1	P4	√	D3
49	2	P3	P2	4	-
50	2	R3	R4	1	VREF
51	2	R1	T3	√	-
52	3	U4	U2	1	VREF
53	3	U1	V3	4	-
54	3	V4	V2	√	VREF
55	3	W3	W4	1	-
56	3	Y1	Y3	1	-
57	3	Y4	Y2	4	-
58	3	AA3	AB1	√	D5
59	3	AB3	AB4	√	VREF
60	3	AD1	AC3	1	VREF
61	3	AC4	AD2	4	-
62	3	AD3	AD4	√	VREF
63	3	AF2	AE3	1	-
64	3	AE4	AG1	5	-
65	3	AG2	AF3	1	VREF
66	3	AF4	AH1	4	-
67	3	AH2	AG3	3	-
68	3	AG4	AJ2	√	INIT
69	4	AJ4	AK3	√	-
70	4	AH5	AK4	1	-
71	4	AJ5	AH6	√	-
72	4	AL4	AK5	√	VREF
73	4	AJ6	AH7	2	-
74	4	AL5	AK6	√	-
75	4	AJ7	AL6	√	VREF
76	4	AH9	AJ8	1	-
77	4	AK8	AJ9	1	VREF
78	4	AL8	AK9	√	VREF
79	4	AK10	AL10	√	-

Table 13: BG432 Differential Pin Pair Summary
XCV300E, XCV400E, XC600E

Pair	Bank	P Pin	N Pin	AO	Other Functions
80	4	AH12	AK11	√	-
81	4	AJ12	AK12	√	-
82	4	AH13	AJ13	√	-
83	4	AL13	AK14	√	VREF
84	4	AH14	AJ14	1	-
85	4	AK15	AJ15	1	VREF
86	5	AH15	AL17	NA	IO_LVDS_DLL
87	5	AK17	AJ17	1	VREF
88	5	AH17	AK18	1	-
89	5	AL19	AJ18	√	VREF
90	5	AH18	AL20	√	-
91	5	AK20	AH19	√	-
92	5	AJ20	AK21	√	-
93	5	AJ21	AL22	√	-
94	5	AJ22	AK23	√	VREF
95	5	AH22	AL24	1	VREF
96	5	AK24	AH23	1	-
97	5	AK25	AJ25	√	VREF
98	5	AL26	AK26	√	-
99	5	AH25	AL27	2	-
100	5	AJ26	AK27	√	VREF
101	5	AH26	AL28	√	-
102	5	AJ27	AK28	1	-
103	6	AH30	AJ30	√	-
104	6	AH31	AG28	3	-
105	6	AG30	AG29	4	-
106	6	AG31	AF28	1	VREF
107	6	AF30	AF29	5	-
108	6	AF31	AE28	1	-
109	6	AD28	AE30	√	VREF
110	6	AD31	AD30	4	-
111	6	AC29	AC28	1	VREF

BG560 Differential Pin Pairs

Virtex-E devices have differential pin pairs that can also provide other functions when not used as a differential pair. A ✓ in the AO column indicates that the pin pair can be used as an asynchronous output for all devices provided in this package. Pairs with a note number in the AO column are device dependent. They can have asynchronous outputs if the pin pair are in the same CLB row and column in the device. Numbers in this column refer to footnotes that indicate which devices have pin pairs that can be asynchronous outputs. The Other Functions column indicates alternative function(s) not available when the pair is used as a differential pair or differential clock.

Table 15: BG560 Differential Pin Pair Summary
XCV400E, XCV600E, XCV1000E, XCV1600E, XCV2000E

Pair	Bank	P Pin	N Pin	AO	Other Functions
Global Differential Clock					
0	4	AL17	AM17	NA	IO_DLL_L15P
1	5	AJ17	AM18	NA	IO_DLL_L15N
2	1	D17	E17	NA	IO_DLL_L21P
3	0	A17	C18	NA	IO_DLL_L21N
IO LVDS					
Total Outputs: 183, Asynchronous Outputs: 87					
0	0	D29	E28	8	VREF
1	0	A31	D28	✓	-
2	0	C29	E27	✓	VREF
3	0	D27	B30	3	-
4	0	B29	E26	✓	-
5	0	C27	D26	✓	VREF
6	0	A28	E25	9	VREF
7	0	C26	D25	7	-
8	0	B26	E24	7	VREF
9	0	D24	C25	2	-
10	0	A25	E23	✓	VREF
11	0	B24	D23	✓	-
12	0	C23	E22	8	-
13	0	D22	A23	✓	-
14	0	B22	E21	✓	VREF
15	0	C21	D21	3	-

Table 15: BG560 Differential Pin Pair Summary
XCV400E, XCV600E, XCV1000E, XCV1600E, XCV2000E

Pair	Bank	P Pin	N Pin	AO	Other Functions
16	0	E20	B21	✓	-
17	0	C20	D20	✓	VREF
18	0	E19	B20	9	-
19	0	C19	D19	7	-
20	0	D18	A19	7	VREF
21	1	E17	C18	NA	IO_LVDS_DLL
22	1	B17	C17	2	VREF
23	1	D16	B16	7	VREF
24	1	C16	E16	7	-
25	1	C15	A15	9	-
26	1	E15	D15	✓	VREF
27	1	D14	C14	✓	-
28	1	E14	A13	3	-
29	1	D13	C13	✓	VREF
30	1	E13	C12	✓	-
31	1	D12	A11	8	-
32	1	C11	B11	✓	-
33	1	D11	B10	✓	VREF
34	1	A9	C10	10	-
35	1	D10	C9	7	VREF
36	1	B8	A8	7	-
37	1	C8	E10	5	VREF
38	1	A6	B7	✓	VREF
39	1	D8	C7	✓	-
40	1	B5	A5	11	-
41	1	D7	C6	✓	VREF
42	1	B4	A4	✓	-
43	1	E7	C5	12	VREF
44	1	A2	D6	✓	CS
45	2	D4	E4	✓	DIN, D0
46	2	F5	B3	17	VREF

Table 20: FG676 — XCV400E, XCV600E

Bank	Pin Description	Pin #
NA	NC	L2
NA	NC	F6
NA	NC	F25
NA	NC	F21
NA	NC	F2
NA	NC	C26
NA	NC	C25
NA	NC	C2
NA	NC	C1
NA	NC	B6
NA	NC	B26
NA	NC	B24
NA	NC	B21
NA	NC	B16
NA	NC	B11
NA	NC	B1
NA	NC	AF25
NA	NC	AF24
NA	NC	AF2
NA	NC	AE6
NA	NC	AE3
NA	NC	AE26
NA	NC	AE24
NA	NC	AE21
NA	NC	AE16
NA	NC	AE14
NA	NC	AE11
NA	NC	AE1
NA	NC	AD25
NA	NC	AD2
NA	NC	AD1
NA	NC	AA6
NA	NC	AA25
NA	NC	AA21
NA	NC	AA2
NA	NC	A3
NA	NC	A25

Table 20: FG676 — XCV400E, XCV600E

Bank	Pin Description	Pin #
NA	NC	A2
NA	NC	A15
NA	VCCINT	G7
NA	VCCINT	G20
NA	VCCINT	H8
NA	VCCINT	H19
NA	VCCINT	J9
NA	VCCINT	J10
NA	VCCINT	J11
NA	VCCINT	J16
NA	VCCINT	J17
NA	VCCINT	J18
NA	VCCINT	K9
NA	VCCINT	K18
NA	VCCINT	L9
NA	VCCINT	L18
NA	VCCINT	T9
NA	VCCINT	T18
NA	VCCINT	U9
NA	VCCINT	U18
NA	VCCINT	V9
NA	VCCINT	V10
NA	VCCINT	V11
NA	VCCINT	V16
NA	VCCINT	V17
NA	VCCINT	V18
NA	VCCINT	Y7
NA	VCCINT	Y20
NA	VCCINT	W8
NA	VCCINT	W19
0	VCCO	J13
0	VCCO	J12
0	VCCO	H9
0	VCCO	H12
0	VCCO	H11

Table 26: FG900 — XCV600E, XCV1000E, XCV1600E

Bank	Pin Description	Pin #
2	IO_L99P_YY	N26
2	IO_L99N_YY	P28
2	IO_L100P	P29
2	IO_L100N	N24
2	IO_L101P_YY	P22
2	IO_L101N_YY	R26
2	IO_VREF_L102P_YY	P25
2	IO_L102N_YY	R29
2	IO_L103P_YY	R21 ⁴
2	IO_L103N_YY	R28 ³
2	IO_VREF_L104P_YY	R25 ²
2	IO_L104N_YY	T30
2	IO_L105P_YY	P24 ⁴
2	IO_L105N_YY	R27 ³
2	IO_L106P	R24
3	IO	T22 ⁴
3	IO	T24 ⁴
3	IO	T26 ⁴
3	IO	T29 ⁴
3	IO	U26 ⁵
3	IO	V23 ⁴
3	IO	V25 ⁴
3	IO	V30 ⁵
3	IO	Y21 ⁴
3	IO	AA26 ⁴
3	IO	AA23 ⁴
3	IO	AB27 ⁴
3	IO	AB29 ⁴
3	IO	AC28 ⁵
3	IO	AD26 ⁴
3	IO	AD29 ⁵
3	IO	AE27 ⁵
3	IO_L106N	U29
3	IO_L107P_YY	R22
3	IO_VREF_L107N_YY	T27 ²
3	IO_L108P_YY	R23

Table 26: FG900 — XCV600E, XCV1000E, XCV1600E

Bank	Pin Description	Pin #
3	IO_L108N_YY	T28
3	IO_L109P_YY	T21
3	IO_VREF_L109N_YY	T25
3	IO_L110P_YY	U28
3	IO_L110N_YY	U30
3	IO_L111P	T23
3	IO_L111N	U27
3	IO_L112P_YY	U25
3	IO_L112N_YY	V27
3	IO_D4_L113P_YY	U24
3	IO_VREF_L113N_YY	V29
3	IO_L114P	W30
3	IO_L114N	U22
3	IO_L115P_YY	U21
3	IO_L115N_YY	W29
3	IO_L116P_YY	V26
3	IO_L116N_YY	W27
3	IO_L117P	W26
3	IO_VREF_L117N	Y29 ¹
3	IO_L118P_YY	W25
3	IO_L118N_YY	Y30
3	IO_L119P_Y	V24 ⁴
3	IO_L119N_Y	Y28 ⁴
3	IO_L120P_YY	AA30
3	IO_L120N_YY	W24
3	IO_L121P	AA29
3	IO_L121N	V20
3	IO_L122P	Y27 ⁴
3	IO_L122N	W23 ⁴
3	IO_L123P_YY	Y26
3	IO_D5_L123N_YY	AB30
3	IO_D6_L124P_YY	V21
3	IO_VREF_L124N_YY	AA28
3	IO_L125P_YY	Y25
3	IO_L125N_YY	AA27
3	IO_L126P_YY	W22
3	IO_L126N_YY	Y23

Table 28: FG1156 — XCV1000E, XCV1600E, XCV2000E, XCV2600E, XCV3200E

Bank	Pin Description	Pin #
2	IO_L92N_Y	H29
2	IO_L93P_YY	J28 ⁴
2	IO_L93N_YY	E33 ⁵
2	IO_L94P_YY	H28
2	IO_L94N_YY	H30
2	IO_L95P_Y	H32
2	IO_L95N_Y	K28
2	IO_L96P_Y	L27 ⁴
2	IO_L96N_Y	F33 ⁵
2	IO_L97P_Y	M26
2	IO_L97N_Y	E34
2	IO_VREF_L98P_YY	H31
2	IO_L98N_YY	G32
2	IO_L99P_YY	N25 ⁴
2	IO_L99N_YY	J31 ⁵
2	IO_L100P_YY	J30
2	IO_L100N_YY	G33
2	IO_VREF_L101P_Y	H34 ²
2	IO_L101N_Y	J29
2	IO_L102P	M27 ⁴
2	IO_L102N	H33 ⁵
2	IO_L103P_Y	K29
2	IO_L103N_Y	J34
2	IO_VREF_L104P_YY	L29
2	IO_L104N_YY	J33
2	IO_L105P_YY	M28
2	IO_L105N_YY	K34
2	IO_L106P_Y	N27
2	IO_L106N_Y	L34
2	IO_VREF_L107P_YY	K33
2	IO_D1_L107N_YY	P26
2	IO_L108P_Y	R25
2	IO_L108N_Y	M34
2	IO_L109P_Y	L31

Table 28: FG1156 — XCV1000E, XCV1600E, XCV2000E, XCV2600E, XCV3200E

Bank	Pin Description	Pin #
2	IO_L109N_Y	L33
2	IO_L110P_Y	P27
2	IO_L110N_Y	M33
2	IO_L111P	M31
2	IO_L111N	R26
2	IO_L112P_Y	N30
2	IO_L112N_Y	P28
2	IO_VREF_L113P_Y	N29
2	IO_L113N_Y	N33
2	IO_L114P_YY	T25 ⁴
2	IO_L114N_YY	N34 ⁵
2	IO_L115P_YY	P34
2	IO_L115N_YY	R27
2	IO_L116P_Y	P29
2	IO_L116N_Y	P31
2	IO_L117P_Y	P33 ⁴
2	IO_L117N_Y	T26 ⁵
2	IO_L118P_Y	R34
2	IO_L118N_Y	R28
2	IO_VREF_L119P_YY	N31
2	IO_D3_L119N_YY	N32
2	IO_L120P_YY	P30 ⁴
2	IO_L120N_YY	R33 ⁵
2	IO_L121P_YY	R29
2	IO_L121N_YY	T34
2	IO_L122P_Y	R30
2	IO_L122N_Y	T30
2	IO_L123P	T28 ⁴
2	IO_L123N	R31 ⁵
2	IO_L124P_Y	T29
2	IO_L124N_Y	U27
2	IO_VREF_L125P_YY	T31
2	IO_L125N_YY	T33
2	IO_L126P_YY	U28

Table 28: FG1156 — XCV1000E, XCV1600E, XCV2000E, XCV2600E, XCV3200E

Bank	Pin Description	Pin #
5	IO_L239P_Y	AP9
5	IO_L239N_Y	AK11
5	IO_L240P_YY	AL11
5	IO_VREF_L240N_YY	AL10
5	IO_L241P_YY	AE13
5	IO_L241N_YY	AM9
5	IO_L242P	AF12 ⁵
5	IO_L242N	AP8 ⁴
5	IO_L243P_Y	AL9
5	IO_VREF_L243N_Y	AH11 ²
5	IO_L244P_Y	AF11
5	IO_L244N_Y	AN8
5	IO_L245P_Y	AM8 ⁵
5	IO_L245N_Y	AG11 ⁴
5	IO_L246P_YY	AL8
5	IO_VREF_L246N_YY	AK9
5	IO_L247P_YY	AH10
5	IO_L247N_YY	AN7
5	IO_L248P	AE12 ⁵
5	IO_L248N	AJ9 ⁴
5	IO_L249P_Y	AM7
5	IO_L249N_Y	AL7
5	IO_L250P_Y	AG10
5	IO_L250N_Y	AN6
5	IO_L251P_YY	AK8 ⁵
5	IO_L251N_YY	AH9 ⁴
5	IO_L252P_YY	AP5
5	IO_VREF_L252N_YY	AJ8
5	IO_L253P_YY	AE11
5	IO_L253N_YY	AN5
5	IO_L254P_Y	AF10
5	IO_L254N_Y	AM6
5	IO_L255P_Y	AL6
5	IO_VREF_L255N_Y	AG9

Table 28: FG1156 — XCV1000E, XCV1600E, XCV2000E, XCV2600E, XCV3200E

Bank	Pin Description	Pin #
5	IO_L256P_Y	AH8
5	IO_L256N_Y	AP4
5	IO_L257P_Y	AN4
5	IO_L257N_Y	AJ7
5	IO_L258P_YY	AM5
5	IO_L258N_YY	AK6
6	IO	T1
6	IO	V2
6	IO	V3
6	IO	V5 ³
6	IO	V8 ³
6	IO	AA10 ³
6	IO	AB5 ³
6	IO	AB7 ³
6	IO	AB9 ³
6	IO	AD7 ³
6	IO	AD8 ³
6	IO	AE2
6	IO	AE4
6	IO	AJ4 ³
6	IO	AH5 ³
6	IO_L259N_YY	AH6
6	IO_L259P_YY	AF8
6	IO_L260N_Y	AE9
6	IO_L260P_Y	AK3
6	IO_L261N_Y	AD10
6	IO_L261P_Y	AL2
6	IO_VREF_L262N_Y	AL1
6	IO_L262P_Y	AH4
6	IO_L263N	AG6
6	IO_L263P	AK1
6	IO_L264N_Y	AF7
6	IO_L264P_Y	AK2

Table 28: FG1156 — XCV1000E, XCV1600E, XCV2000E, XCV2600E, XCV3200E

Bank	Pin Description	Pin #
NA	GND	AP2
NA	GND	AN3
NA	GND	AM20
NA	GND	AK30
NA	GND	AG8
NA	GND	AC29
NA	GND	Y3
NA	GND	Y32
NA	GND	W21
NA	GND	V21
NA	GND	T8
NA	GND	T27
NA	GND	R21
NA	GND	P21
NA	GND	H19
NA	GND	F29
NA	GND	C11
NA	GND	B3
NA	GND	A32
NA	GND	AP3
NA	GND	AN32
NA	GND	AM24
NA	GND	AJ6
NA	GND	AG16
NA	GND	AA14
NA	GND	Y14
NA	GND	W8
NA	GND	W27
NA	GND	U14
NA	GND	T14
NA	GND	R3
NA	GND	R32
NA	GND	M6
NA	GND	H27

Table 28: FG1156 — XCV1000E, XCV1600E, XCV2000E, XCV2600E, XCV3200E

Bank	Pin Description	Pin #
NA	GND	E5
NA	GND	C15
NA	GND	B32
NA	GND	A33
NA	GND	AP7
NA	GND	AN33
NA	GND	AM32
NA	GND	AJ12
NA	GND	AG19
NA	GND	AA15
NA	GND	Y15
NA	GND	W14
NA	GND	V14
NA	GND	U15
NA	GND	T15
NA	GND	R14
NA	GND	P14
NA	GND	M29
NA	GND	G1
NA	GND	E18
NA	GND	C20
NA	GND	B33
NA	GND	A34
NA	GND	AP28
NA	GND	AN34
NA	GND	AM33
NA	GND	AJ23
NA	GND	AG27
NA	GND	AA16
NA	GND	Y16
NA	GND	W15
NA	GND	V15
NA	GND	U16
NA	GND	T16

Table 29: FG1156 Differential Pin Pair Summary:
XCV1000E, XCV1600E, XCV2000E, XCV2600E, XCV3200E

Pair	Bank	P Pin	N Pin	AO	Other Functions
231	5	AH14	AP12	3200 2600 2000 1600 1000	-
232	5	AJ14	AL14	3200 2600 1000	-
233	5	AF13	AN12	3200 2000 1000	-
234	5	AF14	AP11	3200 2000 1000	-
235	5	AN11	AH13	3200 1600 1000	-
236	5	AM12	AL12	3200 2600 2000 1600 1000	-
237	5	AJ13	AP10	3200 2600 2000 1600 1000	VREF
238	5	AK12	AM10	2600 1600 1000	-
239	5	AP9	AK11	2600 1600 1000	-
240	5	AL11	AL10	3200 2600 2000 1600 1000	VREF
241	5	AE13	AM9	3200 2600 2000 1600 1000	-
242	5	AF12	AP8	3200 2600	-
243	5	AL9	AH11	3200 2000 1000	VREF
244	5	AF11	AN8	3200 2000 1000	-
245	5	AM8	AG11	3200 1600	-
246	5	AL8	AK9	3200 2600 2000 1600 1000	VREF
247	5	AH10	AN7	3200 2600 2000 1600 1000	-
248	5	AE12	AJ9	3200 2600	-
249	5	AM7	AL7	3200 1000	-
250	5	AG10	AN6	3200 1000	-

Table 29: FG1156 Differential Pin Pair Summary:
XCV1000E, XCV1600E, XCV2000E, XCV2600E, XCV3200E

Pair	Bank	P Pin	N Pin	AO	Other Functions
251	5	AK8	AH9	2000 1600	-
252	5	AP5	AJ8	3200 2600 2000 1600 1000	VREF
253	5	AE11	AN5	3200 2600 2000 1600 1000	-
254	5	AF10	AM6	3200 2600 1000	-
255	5	AL6	AG9	3200 2000 1000	VREF
256	5	AH8	AP4	3200 2000 1000	-
257	5	AN4	AJ7	3200 1600 1000	-
258	5	AM5	AK6	3200 2600 2000 1600 1000	-
259	6	AF8	AH6	3200 2600 2000 1600 1000	-
260	6	AK3	AE9	3200 2600 2000	-
261	6	AL2	AD10	2600 2000 1000	-
262	6	AH4	AL1	3200 2600 1600 1000	VREF
263	6	AK1	AG6	2600 1600	-
264	6	AK2	AF7	3200 2600 1600 1000	-
265	6	AG5	AJ3	2600 2000 1000	VREF
266	6	AJ2	AD9	3200 2600 2000 1600	-
267	6	AH2	AC10	3200 2600 2000 1600 1000	-
268	6	AF5	AH3	3200 2600 1600 1000	-
269	6	AG3	AE8	3200 2600 2000	-